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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Group Art Unit: To Be Assigned Examiner: To Be Assigned

Ιn	Re	PΔ	FNT	APPI	JCA'	TION	Of:

Applicant : Hirokazu ASAHARA et al.)
U.S. Appln. No. : To Be Assigned)

International Appln. No.: PCT/JP05/012751

International Filing Date: July 11, 2005

Priority Date Claimed: July 12, 2004

) INFORMATION

DISCLOSURE

STATEMENT

For : SEMICONDUCTOR LIGHT EMITTING)

DEVICE .

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

This is an Information Disclosure Statement submitted in compliance with the timing requirements of 37 C.F.R. § 1.97(b)(2).

Attached are copies of three Japanese patent publications and one English-language publication. Any relevance of the Japanese publications can be gleaned from the attached English-language Abstracts and computer translations. Any further relevance of two of the publications also can be gleaned from pages 1-2, and 13 of the specification, where the documents are discussed. All of these publications are listed on the attached Form PTO-1449.

Since this Information Disclosure Statement is being filed with the application, no certification or fee is required, and the requirements of 37 C.F.R. §§ 1.97 and 1.98 are deemed to be fully met as to all documents listed. Consideration of the listed documents is respectfully requested.

Respectfully submitted,

October 5, 2005

Date Robert H. Berdo, Jr. (Reg. No. 38,075) RABIN & BERDO, P.C.

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RHB:tl

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INFORM	FORM PTO-14		Docket No.: Al 391NP	Interna PC	PCT/JP05/0127\$10/551918						
			Applicant:								
			Hirokazu ASAHARA et al.								
			International Filing Date:		Group Art Unit:						
			July 11, 2005		To Be Assigned						
U.S. PATENT DOCUMENTS											
Exam- iner Initial	Document Number	Date	Name	Class	Sub- Class	Filing Date					
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		FORE	IGN PATENT DOCUM	ENTS							
	Document Number	Date	Country	Class	Sub- Class	Trans- lation					
	09-129919	05/16/97	JAPAN			Abstract and computer translation					
	11-121797	04/30/99	JAPAN			Abstract and computer translation					
	2003-224297	08/08/03	JAPAN .			Abstract and computer translation					
OTHER (Including Author, Title, Date, Pertinent Pages, etc.)											
	Ken NAKAHARA et al. "Improved External Efficiency InGaN—Based Light-Emitting Diodes with Transparent Conductive Ga—Doped ZnO as p-Electrodes", Japanese Journal of Applied Physics, Vol. 43, No.2A, 2004, pp. L180—L182.										
Examiner				Date C	onsidered						
			ether or not citation is in considered. Include co								